



Post-Doc Position @ CNR-ISM

SAMOS Laboratory

Roma, Italy

Study of GaN based electronic devices

A call for a one-year post-doc position in the field of electronic devices based on GaN has been published as part of a Regione Lazio Innova project. The project will be conducted at the Istituto di Struttura della Materia of CNR, Via Fosso del Cavaliere 100, Roma, Italy.

The call (code ISM-004-2019-TV-Prot 0066341) is available at:

<https://bandi.urp.cnr.it/assegni/faces/pubblica/RisultatoCercaAssegniPubblica.jsp>

by clicking on: Ricerca Avanzata and then on: “Denominazione”: istituto di struttura della materia

The main activity will concern the study of the interfaces of the thin films grown for the realization of electronic devices based on GaN. The study will be performed using X-ray photoelectron (XPS) spectroscopy and different techniques, to tune the device performances.

Application Deadline: November 15, 2019

For more information about the project, please send an email to **Giorgio Contini:**

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